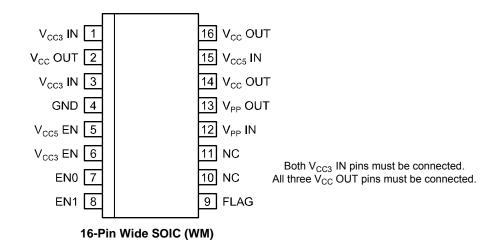
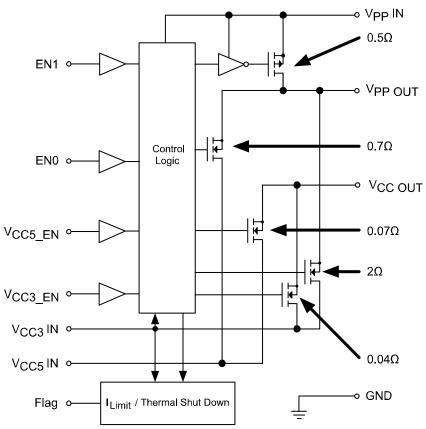
## **Ordering Information**

Part N	umber		
Standard	Pb-Free	Temperature Range	Package
MIC2560-0BWM	MIC2560-0YWM	–40°C to +85°C	16-Pin Wide SOIC
MIC2560-1BWM	MIC2560-1YWM	–40°C to +85°C	16-Pin Wide SOIC

## **Pin Configuration**



## **Logic Block Diagram**



## MIC2560-0 Control Logic Table

Pin 5 V <sub>CC5_EN</sub>	Pin 6 V <sub>CC3_EN</sub>	Pin 8 EN1	Pin 7 EN0	Pins 2 & 14 V <sub>CC OUT</sub>	Pin 13 V <sub>PP OUT</sub>
0	0	0	0	High Z	High Z
0	0	0	1	High Z	High Z
0	0	1	0	High Z	High Z
0	0	1	1	High Z	Clamped to Ground
0	1	0	0	3.3	High Z
0	1	0	1	3.3	3.3
0	1	1	0	3.3	12
0	1	1	1	3.3	Clamped to Ground
1	0	0	0	5	High Z
1	0	0	1	5	5
1	0	1	0	5	12
1	0	1	1	5	Clamped to Ground
1	1	0	0	3.3	High Z
1	1	0	1	3.3	3.3
1	1	1	0	3.3	5
1	1	1	1	3.3	Clamped to Ground

## MIC2560-1 Logic (Compatible with Cirrus Logic CL-PD6710 & CL-PD6720 Controllers)

Pin 5 V <sub>CC5_EN</sub>	Pin 6 V <sub>CC3_EN</sub>	Pin 8 EN1	Pin 7 EN0	Pins 2 & 14 V <sub>CC ОUТ</sub>	Pin 13 V <sub>PP OUT</sub>
0	0	0	0	High Z	Clamped to Ground
0	0	0	1	High Z	High Z
0	0	1	0	High Z	High Z
0	0	1	1	High Z	High Z
0	1	0	0	5	Clamped to Ground
0	1	0	1	5	5
0	1	1	0	5	12
0	1	1	1	5	High Z
1	0	0	0	3.3	Clamped to Ground
1	0	0	1	3.3	3.3
1	0	1	0	3.3	12
1	0	1	1	3.3	High Z
1	1	0	0	High Z	Clamped to Ground
1	1	0	1	High Z	High Z
1	1	1	0	High Z	High Z
1	1	1	1	High Z	High Z

# Absolute Maximum Ratings<sup>(1, 2)</sup>

Power Dissipation, T <sub>AMBIENT</sub> ≤ 25°C	
Derating Factors (To Ambient)	
SOIC4mW/°C	
Storage Temperature (T <sub>s</sub> )–65°C to +150°C	
Maximum Operating Temperature (Die) 125°C	
Operating Temperature (Ambient)40°C to +70°C	
Lead Temperature (soldering, 5sec.)260°C	

Supply Voltage (V <sub>PP IN</sub> )	15V
V <sub>CC3</sub> IN	V <sub>CC5</sub> IN
V <sub>CC5</sub> IN	7.5V
Logic Input Voltages	0.3V to +15V
Output Current (each Output)	
V <sub>PP OUT</sub>	>200mA, Internally Limited
V <sub>PP OUT</sub>	>1A, Internally Limited
V <sub>PP OUT</sub> , Suspend Mode	600mA

## **Electrical Characteristics**(3)

(Over operating temperature range with  $V_{\text{CC3 IN}}$  = 3.3V,  $V_{\text{CC5 IN}}$  = 5.0V,  $V_{\text{PP IN}}$  = 12V unless otherwise specified.)

VH         Logic 1 Input Voltage         2.2         15         V           VIL         Logic 0 Input Voltage         −0.3         0.8         V           Input Current         0V < V <sub>IN</sub> < 5.5V         ±1         μA           VPP Output           Her out High-Impedance Output Leakage Current         Shutdown Mode 1V ≤ V <sub>PP OUT</sub> ≤ 12V         1         10         μA           Inpesc         Short Circuit Current Limit         V <sub>PP OUT</sub> ≤ 12V         0.2         A           Ro         Switch Resistance, Inperor = -100mA (sourcing)         select V <sub>PP OUT</sub> = 5V         0.55         1         Ω           Switch Resistance, Inperor = 50µA         select V <sub>PP OUT</sub> = 5V         0.7         1         Ω         Ω           V <sub>PP</sub> Switching Time         V <sub>P</sub> Switching Time         V <sub>PP OUT</sub> = hi-Z to 5V         50         µs         ½         ¾         ½         ¾         ½         ¾         ½         ¾         ½         ¾         ½         ¾         ¾         ¾	Symbol	Parameter	Condition	Min	Тур	Max	Units
ViL         Logic 0 Input Voltage         —0.3         0.8         V           I <sub>IN</sub> Input Current         0V < V <sub>IN</sub> < 5.5V         ±1         µA           VPP Output           High-Impedance Output Leakage Current         1 V ≤ V <sub>PP OUT</sub> ≤ 12V         1         10         µA           IPPSC         Short Circuit Current Limit         V <sub>PP OUT</sub> = 0         0.2         A           Ro         Switch Resistance, I <sub>PP OUT</sub> = −100mA (sourcing)         select V <sub>PP OUT</sub> = 12V         0.55         1         Ω           select V <sub>PP OUT</sub> = 5V         0.7         1         Ω         select V <sub>PP OUT</sub> = 5V         0.7         1         Ω           select V <sub>PP OUT</sub> = 5U         0.75         2         kΩ         N         N         0.75         2         kΩ         N <th>Input</th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th>	Input						
Input Current   0V < V <sub>IN</sub> < 5.5V   ±1 μA   μA	V <sub>IH</sub>	Logic 1 Input Voltage		2.2		15	V
VPP Output           Inersout Hi-Z         High-Impedance Output Leakage Current         Shutdown Mode 1 V ≤ V <sub>PP OUT</sub> ≤ 12V         1         10         µA           Inersoc Short Circuit Current Limit         V <sub>PP OUT</sub> ≤ 12V         0.2         A           Ro         Switch Resistance, Improut = -100mA (sourcing)         select V <sub>PP OUT</sub> = 12V         0.55         1         Ω           Switch Resistance, Improut = 50µA         select V <sub>PP OUT</sub> = 5V         0.7         1         Ω           V <sub>PP</sub> Switching Time         select V <sub>PP OUT</sub> = clamped to ground         0.75         2         kΩ           V <sub>PP</sub> Switching Time         V <sub>PP OUT</sub> = hi-Z to 5V         50         µs           ta         Output Turn-On Rise Time         V <sub>PP OUT</sub> = hi-Z to 3.3V         40         µs           ta         Output Turn-On Rise Time         V <sub>PP OUT</sub> = hi-Z to 12V         300         µs           ta         Output Rise Time         V <sub>PP OUT</sub> = hi-Z to 12V         300         µs           VCC Output         V <sub>PP OUT</sub> = 3.3V or 5V to 12V         300         µs           VCC Output         Input put put put put put put put put put	V <sub>IL</sub>	Logic 0 Input Voltage		-0.3		0.8	V
High-Impedance Output   High-Impedance Output   Hizer   Hiz	I <sub>IN</sub>	Input Current	0V < V <sub>IN</sub> < 5.5V			±1	μA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VPP Outp	ut	·	<u> </u>			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>PP OUT</sub> Hi-Z				1	10	μA
	I <sub>PPSC</sub>	Short Circuit Current Limit	V <sub>PP OUT</sub> = 0		0.2		Α
	Ro	•	select V <sub>PP OUT</sub> = 12V		0.55	1	Ω
		$I_{PP OUT} = -100 \text{mA} \text{ (sourcing)}$	select V <sub>PP OUT</sub> = 5V		0.7	1	Ω
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			select V <sub>PP OUT</sub> = 3.3V		2	3	Ω
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			select V <sub>PP OUT</sub> = clamped to ground		0.75	2	kΩ
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V <sub>PP</sub> Switc	hing Time	·	<u> </u>			
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	t <sub>1</sub>	Output Turn-On Rise Time	V <sub>PP OUT</sub> = hi-Z to 5V		50		μs
t4     Output Rise Time $V_{PP OUT} = 3.3V \text{ or } 5V \text{ to } 12V$ 300     μs       VCC Output $I_{CC OUT}$ High Impedance Output Leakage Current, Note 3 $1V \le V_{CC OUT} \le 5V$ 1     10 $\mu A$ $I_{CCSC}$ Short Circuit Current Limit $V_{CC OUT} = 0$ 1     2     A $R_O$ Switch Resistance, $V_{CC OUT} = 5.0V$ Switch Resistance, $V_{CC OUT} = -1000$ mA (sourcing)     70     100 $m\Omega$ $V_{CC OUT} = 3.3V$ Vcc Switching Time $V_{CC OUT} = 0V$ to 3.3V, IOUT = 1A     100     600 $\mu$ s $V_{CC OUT} = 0V$ to 5.0V, IOUT = 1A     100     500 $\mu$ s $V_{CC OUT} = 0V$ to 5.0V, IOUT = 1A     100     500 $\mu$ s $V_{CC OUT} = 0V$ to 5.0V, IOUT = 1A     100     500 $\mu$ s $V_{CC OUT} = 0V$ to 5.0V, IOUT = 1A     100     500 $\mu$ s	t <sub>2</sub>	Output Turn-On Rise Time	V <sub>PP OUT</sub> = hi-Z to 3.3V		40		μs
VCC Output $I_{CCOUT}$ High Impedance Output Leakage Current, Note 3 $1V \le V_{CCOUT} \le 5V$ 1 $10$ $\mu A$ $I_{CCSC}$ Short Circuit Current Limit $V_{CCOUT} = 0$ 1       2       A $R_0$ Switch Resistance, $V_{CCOUT} = 5.0V$ $I_{CCOUT} = -1000$ mA (sourcing)       70 $100$ $m\Omega$ $V_{CCOUT} = 5.0V$ Switch Resistance, $V_{CCOUT} = -1000$ mA (sourcing) $V_{CCOUT} = 00$ $V_$	t <sub>3</sub>	Output Turn-On Rise Time	V <sub>PP OUT</sub> = hi-Z to 12V		300		μs
$I_{CC OUT}$ High Impedance Output Leakage Current, Note 3 $1 \lor \le \lor $	t <sub>4</sub>	Output Rise Time	V <sub>PP OUT</sub> = 3.3V or 5V to 12V		300		μs
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VCC Outp	out					
$R_{O} = \begin{cases} Switch \ Resistance, \\ V_{CC \ OUT} = 5.0V \end{cases} \qquad \begin{cases} I_{CC \ OUT} = -1000 mA \ (sourcing) \end{cases} \qquad \begin{cases} 70 & 100 \\ MO \end{cases} \qquad \begin{cases} 70$	I <sub>CC ОИТ</sub> Hi-Z		1V ≤ V <sub>CC OUT</sub> ≤ 5V		1	10	μA
	I <sub>CCSC</sub>	Short Circuit Current Limit	V <sub>CC OUT</sub> = 0	1	2		Α
$V_{CC\ OUT} = 3.3V$ $V_{CC\ OUT} = 3.3V$ $V_{CC\ OUT} = 3.3V$ $V_{CC\ OUT} = 0V\ to\ 3.3V$ , IOUT = 1A       100       600 $\mu_S$ $V_{CC\ OUT} = 0V\ to\ 5.0V$ , IOUT = 1A       100       500 $\mu_S$ $V_{CC\ OUT} = 5.0V\ to\ 3.3V$ 300 $\mu_S$	Ro		I <sub>CC OUT</sub> = –1000mA (sourcing)		70	100	mΩ
$t_1$ Rise Time $V_{CC\ OUT} = 0V\ to\ 3.3V,\ IOUT = 1A$ 100       600 $\mu s$ $t_2$ Rise Time $V_{CC\ OUT} = 0V\ to\ 5.0V,\ IOUT = 1A$ 100       500 $\mu s$ $t_3$ Fall Time $V_{CC\ OUT} = 5.0V\ to\ 3.3V$ 300 $\mu s$		· ·	I <sub>CC OUT</sub> = –1000mA (sourcing)		40	66	mΩ
$t_2$ Rise Time $V_{CC  OUT} = 0V \text{ to } 5.0V, \text{ IOUT = 1A}$ 100       500 $\mu s$ $t_3$ Fall Time $V_{CC  OUT} = 5.0V \text{ to } 3.3V$ 300 $\mu s$	V <sub>CC</sub> Switc	hing Time					
$t_3$ Fall Time $V_{CC\ OUT} = 5.0V\ to\ 3.3V$ 300 µs	t <sub>1</sub>	Rise Time	V <sub>CC OUT</sub> = 0V to 3.3V, IOUT = 1A	100	600		μs
	t <sub>2</sub>	Rise Time	V <sub>CC OUT</sub> = 0V to 5.0V, IOUT = 1A	100	500		μs
t <sub>4</sub> Rise Time V <sub>CC OUT</sub> = hi-Z to 5V 400 μs	t <sub>3</sub>	Fall Time	V <sub>CC OUT</sub> = 5.0V to 3.3V		300		μs
	t <sub>4</sub>	Rise Time	V <sub>CC OUT</sub> = hi-Z to 5V		400		μs

Symbol	Parameter	Condition	Min	Тур	Max	Units
Power Su	pply	•	<u>.</u>	•	•	
I <sub>CC5</sub>	V <sub>CC5 IN</sub> Supply Current	I <sub>CC OUT</sub> = 0		0.01	10	μΑ
I <sub>CC3</sub>	V <sub>CC3 IN</sub> Supply Current	V <sub>CC OUT</sub> = 5V or 3.3V, I <sub>CC OUT</sub> = 0		30	50	μΑ
		V <sub>CC OUT</sub> = hi-Z (Sleep mode)		0.01	10	μΑ
I <sub>PP IN</sub>	V <sub>PP IN</sub> Supply Current (I <sub>PP OUT</sub> = 0)	V <sub>CC</sub> active, V <sub>PP OUT</sub> = 5V or 3.3V		15	50	μΑ
		$V_{PP OUT}$ = hi-Z, 0 or $V_{PP}$		0.01	10	μΑ
V <sub>CC5 IN</sub>	Operating Input Voltage	V <sub>CC5</sub> IN ≥ V <sub>CC3</sub> IN	V <sub>CC3 IN</sub>	5.0	6	V
V <sub>CC3 IN</sub>	Operating Input Voltage	V <sub>CC3 IN</sub> ≤ V <sub>CC5 IN</sub>	2.8	3.3	V <sub>CC3 IN</sub>	V
V <sub>PP IN</sub>	Operating Input Voltage		8.0	12.0	14.5	V
Suspend	Mode (Note 4)	•	<u>.</u>	•	•	•
I <sub>CC3</sub>	Active Mode Current	$V_{PP\ IN}$ = 0V, $V_{CC3}$ = $V_{CC3}$ = 3.3V $V_{CC3}$ = enabled $V_{PP}$ = disabled (hi-Z or 0V)		30		μA
R <sub>ON</sub> V <sub>CC</sub>	V <sub>CC OUT</sub> R <sub>ON</sub>	$V_{PP\ IN}$ = 0V, $V_{CC5}$ = $V_{CC3}$ = 3.3V $V_{CC3}$ = enabled $V_{PP}$ = disabled (hi-Z or 0V)		4.5		Ω

#### Notes:

- 1. Functional operation above the absolute maximum stress ratings is not implied.
- 2. Static-sensitive device. Store only in conductive containers. Handling personnel and equipment should be grounded to prevent damage from static discharge.
- 3. Leakage current after 1,000 hours at 125°C may increase up to five times the initial limit.
- 4. Suspend mode is a pseudo-power-down mode the MIC2560 automatically allows when V<sub>PP IN</sub> = 0V, V<sub>PP OUT</sub> is deselected, and V<sub>CC OUT</sub> =3.3V is selected. Under these conditions, the MIC2560 functions in a reduced capacity mode where V<sub>CC</sub> output of 3.3V is allowed, but at lower current levels (higher switch on-resistance).

### **Application Information**

PCMCIA  $V_{CC}$  and  $V_{PP}$  control is easily accomplished using the MIC2560 voltage selector/switch IC. Four control bits determine  $V_{CC}$  out and  $V_{PP}$  out voltage and standby/operate mode condition.  $V_{PP}$  out output voltages of  $V_{CC}$  (3.3V or 5V),  $V_{PP}$ , or a high impedance state are available. When the  $V_{CC}$  high impedance condition is selected, the device switches into "sleep" mode and draws only nano-amperes of leakage current. An error flag falls low if the output is improper, because of overtemperature or overcurrent faults. Full protection from hot switching is provided which prevents feedback from the  $V_{PP}$  out to the  $V_{CC}$  inputs (from 12V to 5V, for example) by locking out the low voltage switch until  $V_{PP}$  out drops below  $V_{CC}$ . The  $V_{CC}$  output is similarly protected against 5V to 3.3V shoot through.

The MIC2560 is a low-resistance power MOSFET switching matrix that operates from the computer system main power supply. Device logic power is obtained from  $V_{\rm CC3}$  and internal MOSFET drive is obtained from the  $V_{\rm PP\ IN}$  pin (usually +12V) during normal operation. If +12V is not available, the MIC2560 automatically switches into "suspend" mode, where  $V_{\rm CC\ OUT}$  can be switched to 3.3V, but at higher switch resistance. Internal break-before-make switches determine the output voltage and device mode.

#### **Supply Bypassing**

External capacitors are not required for operation. The MIC2560 is a switch and has no stability problems. For best results however, bypass  $V_{\text{CC3 IN}},\,V_{\text{CC5 IN}},\,$  and  $V_{\text{PP IN}}$  inputs with filter capacitors to improve output ripple. As all internal device logic and voltage/current comparison functions are powered from the  $V_{\text{CC3 IN}}$  line, supply bypass of this line is the most critical, and may be necessary in some cases. In the most stubborn layouts, up to  $0.47\mu\text{F}$  may be necessary. Both  $V_{\text{CC OUT}}$  and  $V_{\text{PP OUT}}$  pins may have  $0.01\mu\text{F}$  to  $0.1\mu\text{F}$  capacitors for noise reduction and electrostatic discharge (ESD) damage prevention. Larger values of output capacitor might create current spikes during transitions, requiring larger bypass capacitors on the  $V_{\text{CC3 IN}},\,V_{\text{CC5 IN}},\,$  and  $V_{\text{PP IN}}$  pins.

#### **PCMCIA Implementation**

The MIC2560 is designed for compatibility with the Personal Computer Memory Card International Association's (PCMCIA) Specification, revision 2.1 as well as the PC Card Specification, (March 1995), including the CardBus option.

The Personal Computer Memory Card International Association (PCMCIA) specification requires two  $V_{PP}$  supply pins per PCMCIA slot.  $V_{PP}$  is primarily used for programming Flash (EEPROM) memory cards. The two  $V_{PP}$  supply pins may be programmed to different voltages. Fully implementing PCMCIA specifications requires a MIC2560, a MIC2557 PCMCIA  $V_{PP}$  Switching

Matrix, and a controller. Figure 3 shows this full configuration, supporting both 5.0V and  $3.3V V_{CC}$  operation.

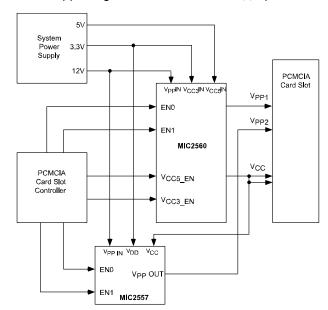


Figure 3. MIC2560 Typical PCMCIA Memory Card Application with Dual V<sub>CC</sub> (5.0V or 3.3V) and separate V<sub>PP1</sub> and V<sub>PP2</sub>.

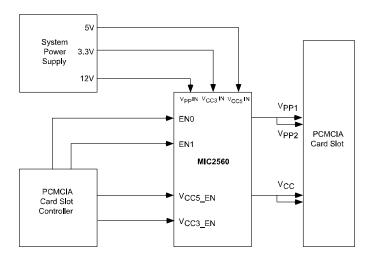


Figure 4. MIC2560 Typical PCMCIA Memory Card Application with Dual  $V_{\rm CC}$  (5.0V or 3.3V). Note that V  $_{\rm PP1}$  and V  $_{\rm PP2}$  are Driven Together.

However, many cost sensitive designs (especially notebook/palmtop computers) connect  $V_{PP1}$  to  $V_{PP2}$  and the MIC2557is not required. This circuit is shown in Figure 4.

When a memory card is initially inserted, it should receive  $V_{\text{CC}}$  — either 3.3V  $\pm$  0.3V or 5.0V  $\pm$ 5%. The initial voltage is determined by a combination of mechanical socket "keys" and voltage sense pins. The card sends a handshaking data stream to the controller, which then determines whether or not this card requires  $V_{\text{PP}}$  and if the card is designed for dual  $V_{\text{CC}}$ . If the card is

compatible with and desires a different  $V_{\text{CC}}$  level, the controller commands this change by disabling  $V_{\text{CC}}$ , waiting at least 100ms, and then re-enabling the other  $V_{\text{CC}}$  voltage.

If no card is inserted or the system is in sleep mode, the controller outputs a ( $V_{\text{CC3 IN}}$ ,  $V_{\text{CC5 IN}}$ ) = (0,0) to the MIC2560, which shuts down  $V_{\text{CC}}$ . This also places the switch into a high impedance output shutdown (sleep) mode, where current consumption drops to nearly zero, with only tiny CMOS leakage currents flowing.

During Flash memory programming with standard (+12V) Flash memories, the PCMCIA controller outputs a (1,0) to the EN0, EN1 control pins of the MIC2560, which connects  $V_{PP\ IN}$  to  $V_{PP\ OUT}$ . The low ON resistance of the MIC2560 switches allow using small bypass capacitors (in some cases, none at all) on the  $V_{CC\ OUT}$ and V<sub>PP OUT</sub> pins, with the main filtering action performed by a large filter capacitor on the input supply voltage to V<sub>PP IN</sub> (usually the main power supply filter capacitor is sufficient). The  $V_{PP\ OUT}$  transition from  $V_{CC}$  to 12.0V typically takes 250µs. After programming is completed, the controller outputs a (EN1, EN0) = (0,1) to the MIC2560, which then reduces  $V_{PP OUT}$  to the  $V_{CC}$  level for read verification. Break-before-make switching action reduces switching transients and lowers maximum current spikes through the switch from the output capacitor. The flag comparator prevents having high voltage on the V<sub>PP OUT</sub> capacitor from contaminating the  $V_{CC}$  inputs, by disabling the low voltage  $V_{PP}$  switches until  $V_{PP\ OUT}$  drops below the  $V_{CC}$  level selected. The lockout delay time varies with the load current and the capacitor on V<sub>PP OUT</sub>. With a 0.1µF capacitor and nominal I<sub>PP OUT</sub>, the delay is approximately 250μs.

Internal drive and bias voltage is derived from  $V_{PP\ IN}$ . Internal device control logic is powered from  $V_{CC3\ IN}$ . Input logic threshold voltages are compatible with common PCMCIA controllers using either 3.3V or 5V supplies. No pull-up resistors are required at the control inputs of the MIC2560.

#### **Output Current and Protection**

MIC2560 output switches are capable of more current than needed in PC Card applications (1A) and meet or exceed all PCMCIA specifications. For system and card protection, output currents are internally limited. For full system protection, long term (millisecond or longer) output short circuits invoke overtemperature shutdown, protecting the MIC2560, the system power supplies, the card socket pins, and the memory card. Overtemperature shutdown typically occurs at a die temperature of 115°C.

#### Single V<sub>cc</sub> Operation

For PC Card slots requiring only a single  $V_{CC}$ , connect  $V_{CC3 IN}$  and  $V_{CC5 IN}$  together and to the system  $V_{CC}$  supply (i.e., Pins 1, 3, and 15 are all connected to system  $V_{CC}$ ).

Either the  $V_{\text{CC5}}$  switch or the  $V_{\text{CC3}}$  switch may be used to enable the card slot  $V_{\text{CC}}$ ; generally the  $V_{\text{CC3}}$  switch is preferred because of its lower ON resistance.

#### **Suspend Mode**

An additional feature in the MIC2560 is a pseudo power-down mode, Suspend Mode, which allows operation without a  $V_{PP\ IN}$  supply. In Suspend Mode, the MIC2560 supplies 3.3V to  $V_{CC\ OUT}$  whenever a  $V_{CC}$  output of 3.3V is enabled by the PCMCIA controller. This mode allows the system designer the ability to turn OFF the  $V_{PP}$  supply generator to save power when it is not specifically required. The PCMCIA card receives  $V_{CC}$  at reduced capacity during Suspend Mode, as the switch resistance rises to approximately  $4.5\Omega$ .

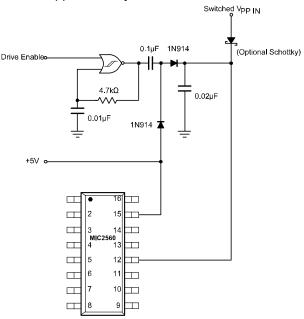
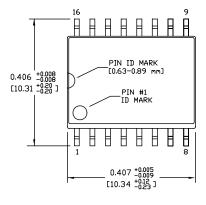


Figure 5. Circuit for Generating Bias Drive for the  $V_{\text{CC}}$  Switches when +12V is Not Readily Available.

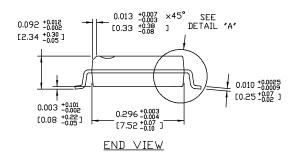
#### High Current V<sub>CC</sub> Operation Without a +12V Supply

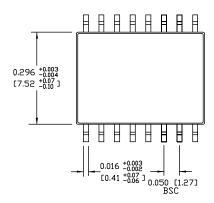
Figure 5 shows the MIC2560 with  $V_{\text{CC}}$  switch bias provided by a simple charge pump. This enables the system designer to achieve full V<sub>CC</sub> performance without a +12V supply, which is often helpful in battery powered systems that only provide +12V when it is needed. These on-demand +12V supplies generally have a quiescent current draw of a few milli-amperes, which is far more than the microamperes used by the MIC2560. The charge pump of figure 5 provides this low current, using about 100 $\mu$ A when enabled. When  $V_{PP OUT}$  =12V is selected, however, the on-demand V<sub>PP</sub> generator must be used, as this charge pump cannot deliver the current required for Flash memory programming. The Schottky diode may not be necessary, depending on the configuration of the on-demand +12V generator and whether any other loads are on this line.

### **Package Information**

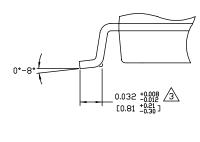


TOP VIEW





BOTTOM VIEW



DETAIL "A"

#### NOTES

1. DIMENSIONS ARE IN INCHESEMM]. 2. CONTROLLING DIMENSION: INCHES.

DIMENSION DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS, EITHER OF WHICH SHALL NOT EXCEED 0.006[0.15] PER SIDE.

16-Pin Wide SOIC (WM)

#### MICREL, INC. 2180 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL +1 (408) 944-0800 FAX +1 (408) 474-1000 WEB http://www.micrel.com

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